Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	17159	(dv/dt snubber ((change variation) adj voltage adj (T time)))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/02 09:05
L2	193	1 same (over\$current overcurrent (over ADJ current))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/02 09:05
L3	111	2 same (protect\$3 limit\$5)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/02 09:06
L6	9	3 same ((power adj (transistor pnp npn mos fet bipolar)))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/02 09:09

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	17159	(dv/dt snubber ((change variation) adj voltage adj (T time)))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/02 11:36
L2	193	L1 same (over\$current overcurrent (over ADJ current))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/02 11:36
L3	111	L2 same (protect\$3 limit\$5)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/02 11:36
S1	221502	(voltage adj (stabiliz\$3 control\$4 regulat\$3))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/11/30 18:30
52	15091	S1 same ((circuit ADJ integrated) IC chip)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/11/30 18:30
S3	103	S2 same (over\$current overcurrent (over ADJ current))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/11/30 18:31
S4	57	S3 same (R resist\$4 potentiometer rheostat impedance)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/11/30 18:32
S5	17159	(dv/dt snubber ((change variation) adj voltage adj (T time)))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/02 09:05

S6	193	S5 same (over\$current overcurrent (over ADJ current))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/02 09:05
S7	111	S6 same (protect\$3 limit\$5)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/02 09:13
S8	9	S7 same ((power adj (transistor pnp npn mos fet bipolar)))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/02 09:09
S9	1	S6 same ((protect\$3 limit\$5) adj ((power adj (transistor pnp npn mos fet bipolar))))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/02 09:14
S10	26	("4933798" "5049790" "5315214" "5373435" "5550433" "5699238" "5705894" "5811941" "5982110").PN. OR ("6211623"). URPN.	US-PGPUB; USPAT; USOCR	OR	ON	2005/12/02 09:15